

# TD62064BP-1, TD62064BF

## 4CH HIGH-CURRENT DARLINGTON SINK DRIVER

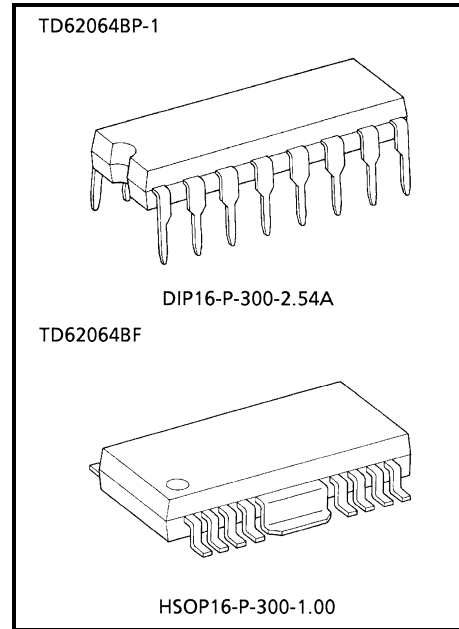
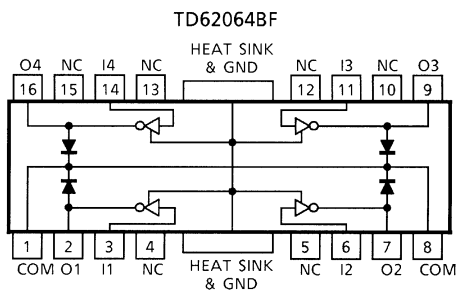
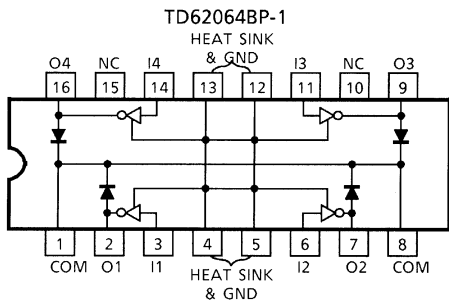
The TD62064BP-1 and TD62064BF are high-voltage, high-current darlington drivers comprised of four NPN darlington pairs. All units feature integral clamp diodes for switching inductive loads.

Applications include relay, hammer, lamp and stepping motor drivers.

### FEATURES

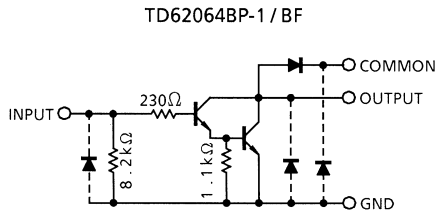
- Package Type BP-1 : DIP16 pin  
BF : HSOP16 pin
- High Output Sustaining Voltage :  $V_{CE(SUS)} = 80\text{ V (min)}$
- Output Current (Single Output) :  $I_{OUT} = 1.5\text{ A / ch (max)}$
- Output Clamp Diodes
- Input Compatible with TTL and 5 V CMOS
- GND and SUB Terminal = Heat Sink

### PIN CONNECTION (TOP VIEW)



Weight  
DIP16-P-300-2.54A: 1.11 g (typ.)  
HSOP16-P-300-1.00: 0.50 g (typ.)

## SCHEMATICS (EACH DRIVER)



Note : The input and output parasitic diodes cannot be used as clamp diodes.

## PRECAUTIONS for USING

- (1) This IC does not include built-in protection circuits for excess current or overvoltage. If this IC is subjected to excess current or overvoltage, it may be destroyed. Hence, the utmost care must be taken when systems which incorporate this IC are designed. Utmost care is necessary in the design of the output line, COMMON and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.
- (2) If a TD62064BP-1/BF is being used to drive an inductive load (such as a motor, solenoid or relay), Toshiba recommends that the diodes (pins 1 and 8) be connected to the secondary power supply pin so as to absorb the counter electromotive force generated by the load. Please adhere to the device's absolute maximum ratings. Toshiba recommends that zener diodes be connected between the diodes (pins 1 and 8) and the secondary power supply pin (as the anode) so as to enable rapid absorption of the counter electromotive force. Again, please adhere to the device's absolute maximum ratings.

## ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Output Sustaining Voltage	$V_{CE(SUS)}$	-0.5 ~ 80	V	
Parasitic Transistor Output Voltage	$V_{CEF}$ (Note 1)	80	V	
Output Current	$I_{OUT}$	1.5	A / ch	
Input Current	$I_{IN}$	50	mA	
Input Voltage	$V_{IN}$	7	V	
Clamp Diode Reverse Voltage	$V_R$	80	V	
Clamp Diode Forward Current	$I_F$	1.5	A	
Power Dissipation	BP-1	$P_D$	1.47 / 2.7 (Note 2)	W
	BF		0.9 / 1.4 (Note 3)	
Operating Temperature	$T_{opr}$	-40 ~ 85	°C	
Storage Temperature	$T_{stg}$	-55 ~ 150	°C	

Note 1: Parasitic Transistor (COMMON - GND - OUTPUT) Output Voltage

Note 2: On Glass Epoxy PCB (50 × 50 × 1.6 mm Cu 50%)

Note 3: On Glass Epoxy PCB (60 × 30 × 1.6 mm Cu 30%)

**RECOMMENDED OPERATING CONDITIONS (Ta = -40~85°C)**

CHARACTERISTIC		SYMBOL	CONDITION	MIN	TYP.	MAX	UNIT
Output Sustaining Voltage		V <sub>CE(SUS)</sub>		0	—	80	V
Output Current	BP-1 (Note 1)	I <sub>OUT</sub>	DC 1 Circuit, Ta = 25°C	0	—	1250	mA / ch
			T <sub>pw</sub> = 25ms 4 Circuits T <sub>j</sub> = 120°C Ta = 85°C	Duty = 10 %	0	—	
	Duty = 50 %			0	—	380	
	Duty = 10 %			0	—	900	
	Duty = 50 %			0	—	170	
BF (Note 2)							
Input Voltage		V <sub>IN</sub>		0	—	5.5	V
	(Output On)	V <sub>IN(ON)</sub>	I <sub>OUT</sub> = 1.25 A	2.5	—	8	V
	(Output Off)	V <sub>IN(OFF)</sub>		0	—	0.4	V
Input Current		I <sub>IN</sub>		0	—	20	mA
Clamp Diode Reverse Voltage		V <sub>R</sub>		0	—	80	V
Clamp Diode Forward Current		I <sub>F</sub>		—	—	1.25	A
Power Dissipation	BP-1	P <sub>D</sub>	Ta = 85°C (Note 1)	—	—	1.4	W
	BF		Ta = 85°C (Note 2)	—	—	0.7	

Note 1: On Glass Epoxy PCB (50 × 50 × 1.6 mm Cu 50%)

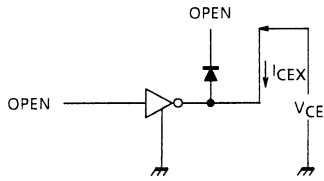
Note 2: On Glass Epoxy PCB (60 × 30 × 1.6 mm Cu 30%)

**ELECTRICAL CHARACTERISTICS (Ta = 25°C unless otherwise noted)**

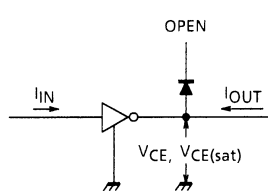
CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT
Output Leakage Current	I <sub>CEX</sub>	1	V <sub>CE</sub> = 80 V, Ta = 25°C	—	—	50	μA
			V <sub>CE</sub> = 80 V, Ta = 85°C	—	—	100	
Output Saturation Voltage	V <sub>CE(sat)</sub>	2	I <sub>OUT</sub> = 1.25 A, V <sub>IN</sub> = 2.4 V	—	—	1.6	V
			I <sub>OUT</sub> = 0.75 A, V <sub>IN</sub> = 2.4 V	—	—	1.25	
DC Current Transfer Ratio	h <sub>FE</sub>	2	V <sub>CE</sub> = 2 V, I <sub>OUT</sub> = 1.25 A	—	1500	—	
Input Voltage (Output On)	V <sub>IN(ON)</sub>	3	I <sub>OUT</sub> = 1.25 A, I <sub>IN</sub> = 2 mA	—	—	2.4	V
Clamp Diode Leakage Current	I <sub>R</sub>	4	V <sub>R</sub> = 80 V, Ta = 25°C	—	—	50	μA
			V <sub>R</sub> = 80 V, Ta = 85°C	—	—	100	
Clamp Diode Forward Voltage	V <sub>F</sub>	5	I <sub>F</sub> = 1.25 A	—	1.5	2.0	V
Input Capacitance	C <sub>IN</sub>	6	V <sub>IN</sub> = 0, f = 1 MHz	—	15	—	pF
Turn-On Delay	t <sub>ON</sub>	7	V <sub>OUT</sub> = 80 V, R <sub>L</sub> = 68 Ω	—	0.1	—	μs
Turn-Off Delay	t <sub>OFF</sub>			—	1.0	—	
Parasitic Transistor Output Voltage	V <sub>CEF</sub>	8	I <sub>CEF</sub> = 150 mA	80	—	—	V

## TEST CIRCUIT

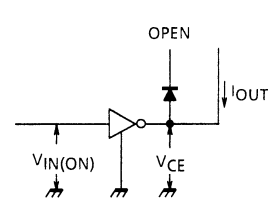
### 1. $I_{CEX}$



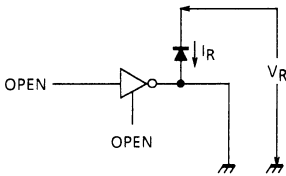
### 2. $V_{CE(sat)}$ , $h_{FE}$



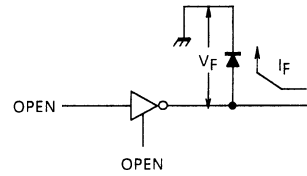
### 3. $V_{IN(ON)}$



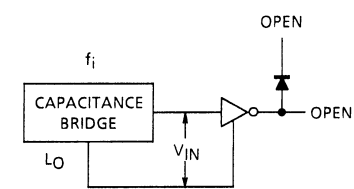
### 4. $I_R$



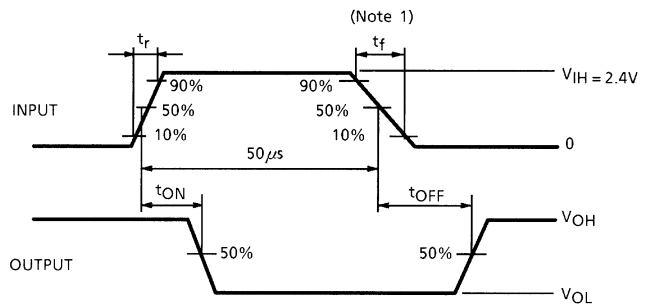
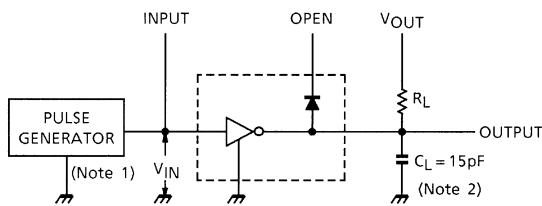
### 5. $V_F$



### 6. $C_{IN}$

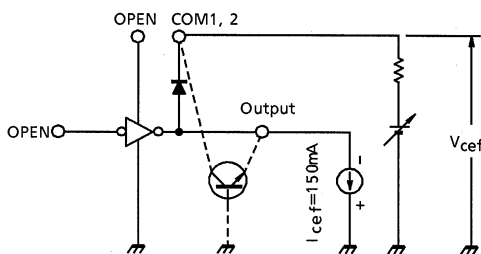


### 7. $t_{ON}$ , $t_{OFF}$

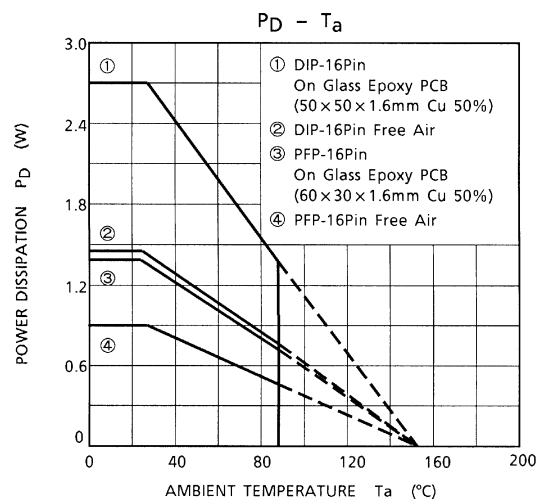
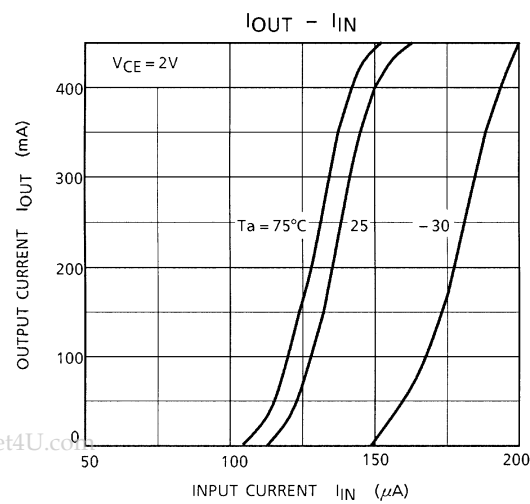
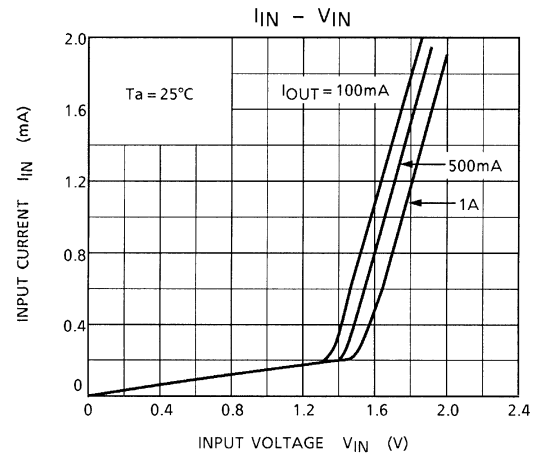
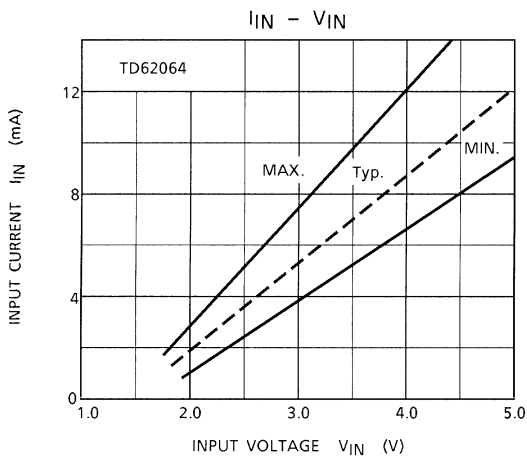
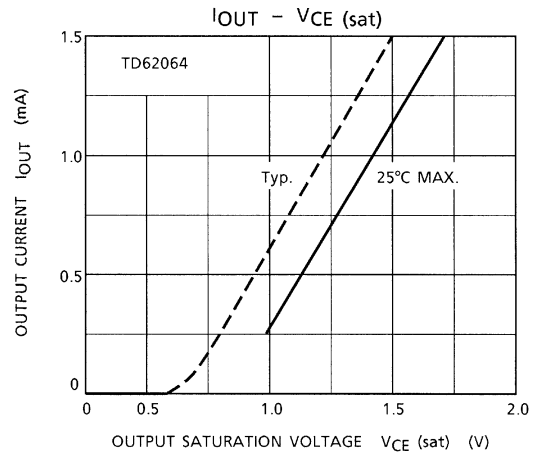
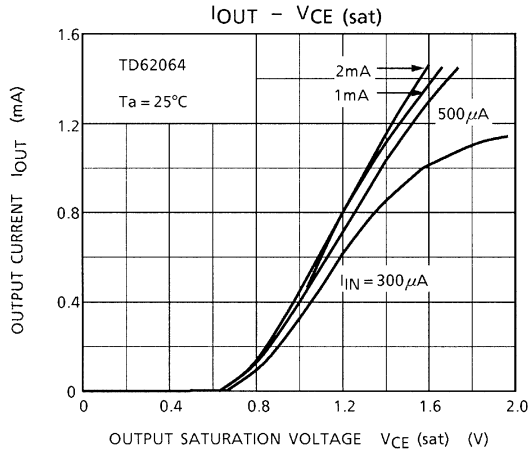


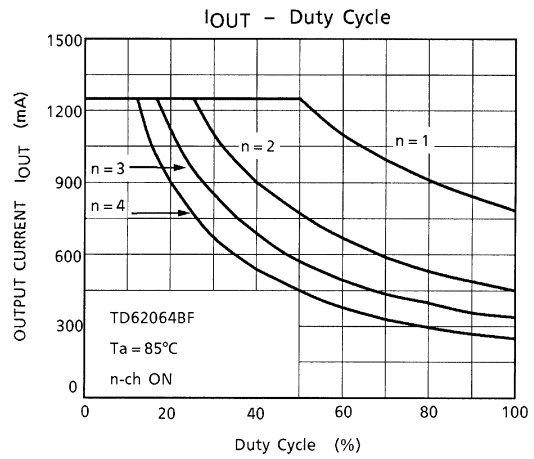
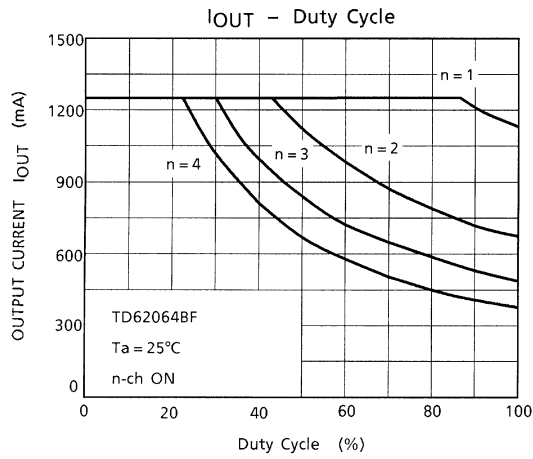
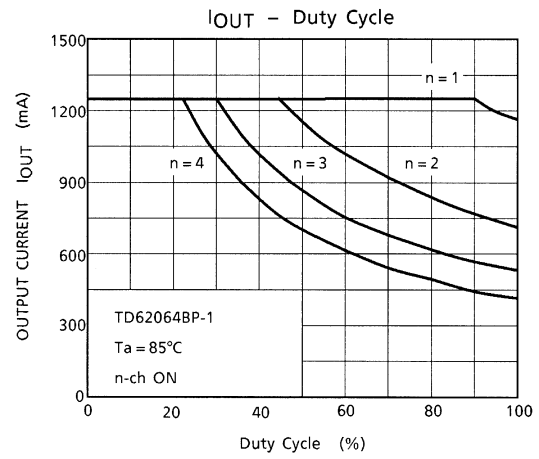
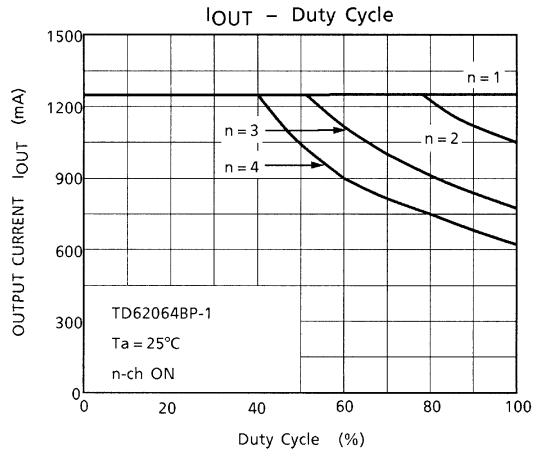
Note 1: Pulse Width 50  $\mu$ s, Duty Cycle 10%  
Output Impedance 50  $\Omega$ ,  $t_r \leq 5$  ns,  $t_f \leq 10$  ns  
Note 2:  $C_L$  includes probe and jig capacitance

### 8. $V_{cef}$



$I_{cef} = 150$ mA (at . Single pulse = 5ms)

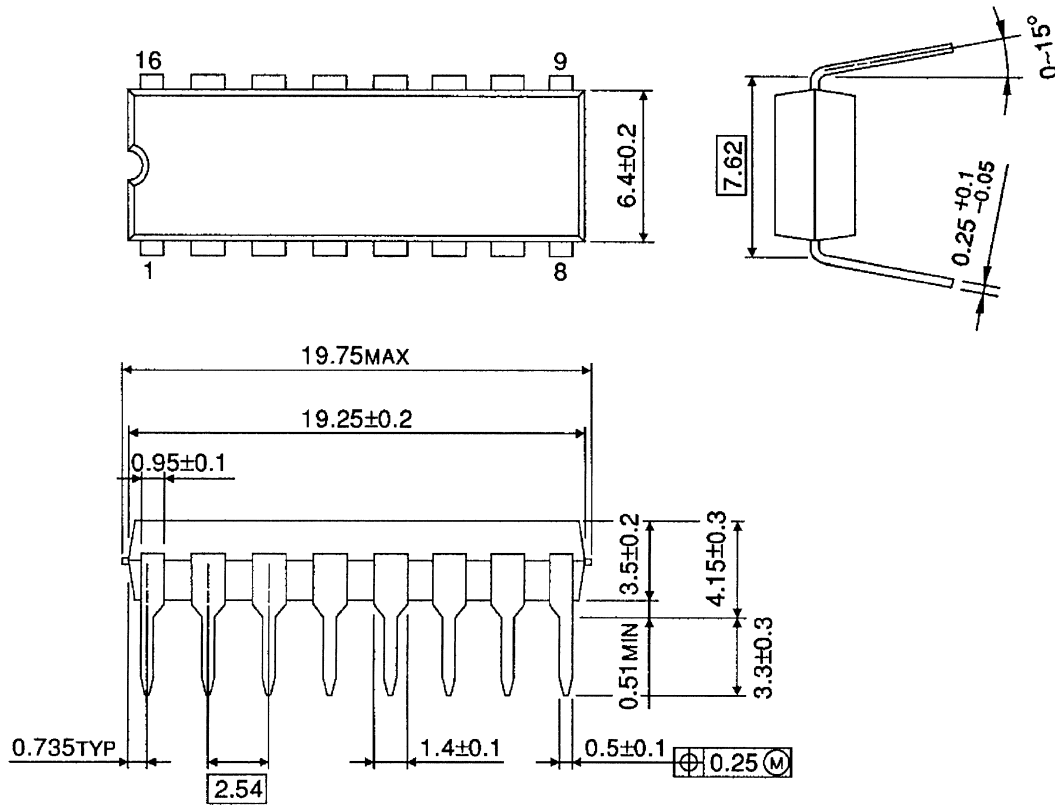




## PACKAGE DIMENSIONS

DIP16-P-300-2.54A

Unit : mm

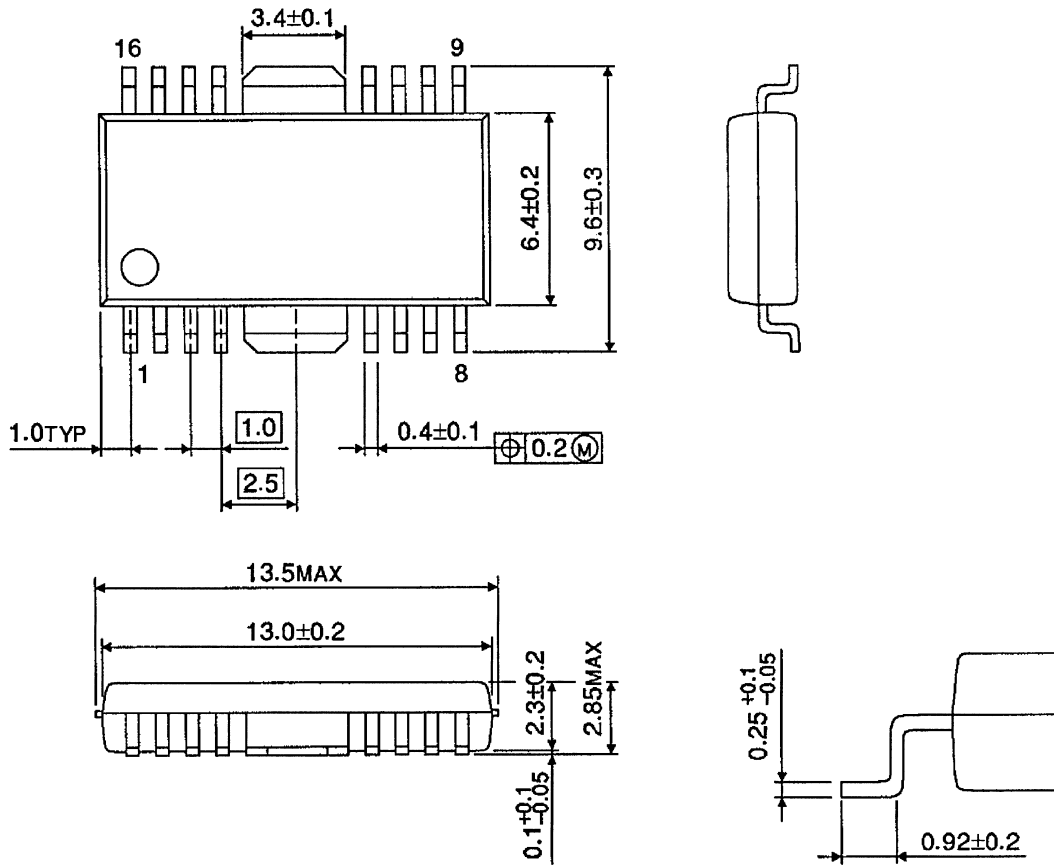


Weight: 1.11 g (typ.)

## PACKAGE DIMENSIONS

HSOP16-P-300-1.00

Unit : mm



Weight: 0.50 g (typ.)



## Notes on Contents

### 1. Equivalent Circuits

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

### 2. Test Circuits

Components in the test circuits are used only to obtain and confirm the device characteristics. These components and circuits are not guaranteed to prevent malfunction or failure from occurring in the application equipment.

## IC Usage Considerations

### Notes on Handling of ICs

- (1) The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings.  
Exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.
- (2) Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of over current and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or load, causing a large current to continuously flow and the breakdown can lead smoke or ignition. To minimize the effects of the flow of a large current in case of breakdown, appropriate settings, such as fuse capacity, fusing time and insertion circuit location, are required.
- (3) If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or the negative current resulting from the back electromotive force at power OFF. IC breakdown may cause injury, smoke or ignition.  
Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
- (4) Do not insert devices in the wrong orientation or incorrectly.  
Make sure that the positive and negative terminals of power supplies are connected properly. Otherwise, the current or power consumption may exceed the absolute maximum rating, and exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.  
In addition, do not use any device that is applied the current with inserting in the wrong orientation or incorrectly even just one time.
- (5) Carefully select external components (such as inputs and negative feedback capacitors) and load components (such as speakers), for example, power amp and regulator.  
If there is a large amount of leakage current such as input or negative feedback condenser, the IC output DC voltage will increase. If this output voltage is connected to a speaker with low input withstand voltage, overcurrent or IC failure can cause smoke or ignition. (The over current can cause smoke or ignition from the IC itself.) In particular, please pay attention when using a Bridge Tied Load (BTL) connection type IC that inputs output DC voltage to a speaker directly.

**Points to Remember on Handling of ICs**

## (1) Heat Radiation Design

In using an IC with large current flow such as power amp, regulator or driver, please design the device so that heat is appropriately radiated, not to exceed the specified junction temperature ( $T_j$ ) at any time and condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, please design the device taking into consideration the effect of IC heat radiation with peripheral components.

## (2) Back-EMF

When a motor rotates in the reverse direction, stops or slows down abruptly, a current flow back to the motor's power supply due to the effect of back-EMF. If the current sink capability of the power supply is small, the device's motor power supply and output pins might be exposed to conditions beyond maximum ratings. To avoid this problem, take the effect of back-EMF into consideration in system design.

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